



**THE DATASHEET OF
EVAL2EDL23I06PJTOB01**



EiceDRIVER™

High voltage gate driver IC

Evaluation Board

Application Note

EVAL-2EDL23I06PJ

Application Note

Rev. 1.0 2014-04-11

Edition 2014-04-11

**Published by Infineon Technologies AG,
81726 Munich, Germany.**

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Revision History: 2014-04 Rev.1.0

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Warnings



The described board is an evaluation board dedicated for laboratory environment only. It operates at high voltages. This board must be operated by qualified, skilled personnel familiar with all applicable safety standards.

1 Introduction

The gate driver evaluation board EVAL-2EDL23I06PJ was developed to show the functionalities and key features of the Infineon IGBT gate driver 2EDL23I06PJ.

The board is available from Infineon in sampling quantities. The properties of this part are described in the datasheet chapter of this document, whereas the remaining paragraphs provide information intended to enable the customer to copy, modify and qualify the design for production, according to their own specific requirements.

The design of the EVAL-2EDL23I06PJ was performed with respect to the environmental conditions described in this document. The design was tested as described in this document, but not qualified regarding manufacturing, lifetime or over the full ambient operating conditions.

The boards provided by Infineon are subjected to functional testing only.

Due to their purpose Evaluation Boards are not subjected to the same procedures regarding Returned Material Analysis (RMA), Process Change Notification (PCN) and Product Discontinuation (PD) as regular products. These Evaluation Boards are used for development support only and should not be used as reference design for volume production.

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2 Design features

2.1 Main features



Figure 1 Top view of the EVAL-2EDL23I06PJ

The EVAL-2EDL23I06PJ contains an Infineon IGBT gate half bridge driver 2EDL23I06PJ and two Infineon IGBTs IKP20N60H3.

The evaluation board provides the following main features

- Short circuit protection by shunt measurement incl. status LED (/FAULT) and latch
- Current measurement with operational amplifier
- Under voltage lock out
- Bootstrap functionality for high side IGBT by using the internal ultra-fast bootstrap diode of the 2EDL23I06PJ
- Deadtime and interlock function integrated in the IGBT gate driver.
- Connector for 15V supply, Reset, High voltage supply, external load
- Internal voltage regulator for 5V supply
- Status LED for 15V supply, /FAULT state
- DC link capacitor

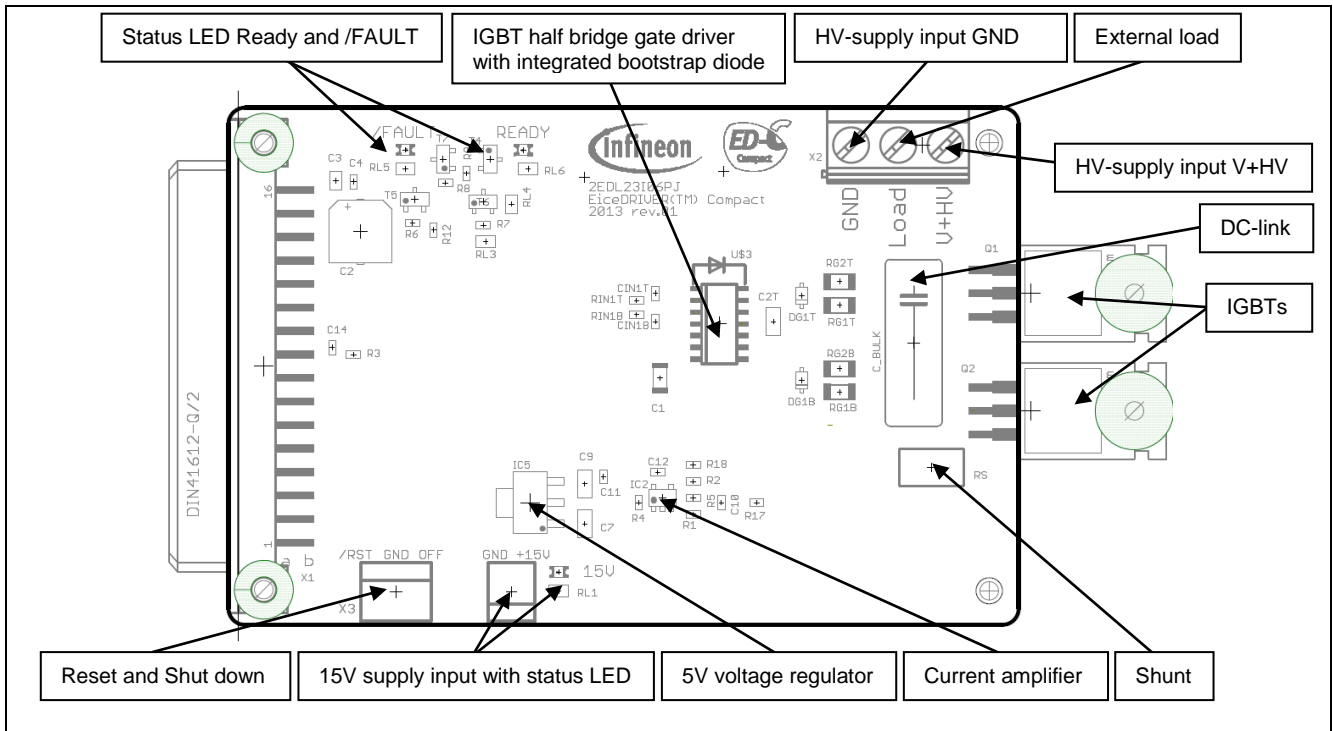


Figure 2 Overview functionalities on top-side

2.2 Board specifications

All values are specified at an ambient temperature of $T_A = 25^\circ\text{C}$

Table 1 Board specifications

| Parameter | Description | Typ. | min | max | Unit |
|---------------|----------------------------------|------|------|------|------|
| V_{DD} | 15V voltage supply | 15 | 13.2 | 17.5 | V |
| V_{bc} | High voltage supply | 320 | - | 450 | V |
| $I_{Out,pk}$ | Single pulse peak output current | - | - | 20 | A |
| $I_{Out,rms}$ | RMS output current | - | - | 4 | A |
| f_p | Switching frequency | 40 | - | 100 | kHz |

2.3 Pin assignment

Table 2 Pin assignment

| Connector name | Pin no. | Pin name | Description |
|----------------|-----------------|----------|----------------|
| RESET | Left terminal | /RST | same as X1-B1 |
| | Middle terminal | GND | same as X1-A16 |
| | Right terminal | OFF | same as X1-B2 |

| | | | |
|------------|----------------|------|---------------------|
| +15V (VDD) | Right terminal | +15V | positive 15V supply |
| | Left terminal | GND | |

| | | | |
|----|-----|------|--|
| X1 | A16 | GND | reference for 15V supply and input signals |
| | B1 | /RST | input – 0V to reset circuit |
| | B2 | /FLT | output over current; OC, 0..15V |
| | B7 | IN_T | non-inverting input top IGBT; 0V off; 5V on |
| | B8 | IN_B | non-inverting input bottom IGBT; 0V off; 5V on |
| | B16 | +5V | positive 5V supply generated from 15V |

*see Figure 21 for connector pin numbering

| | | | |
|------|--|--|--|
| GND | | | reference for high voltage supply (Power-GND, internally connected to GND) |
| V+HV | | | positive high voltage supply (up to 400V related to GND_HV) |
| Load | | | Output HV half bridge (related to GND_HV) for connecting a test load |

3 Electrical features

3.1 Supply voltages +5V and +15V

The supply voltage for the driver output (+15V VDD) has to be supplied externally over the dedicated connector. The digital 5V supply voltage is generated internally by an Infineon voltage regulator. The evaluation board does not provide an overvoltage supply monitoring. The user has to ensure therefore that the voltages are in the correct range. Voltages above the maximum values will lead to damages of the IGBT drivers. The availability of the supply voltage +15V is visible over the green status LED.

The high-side gate driver is supplied over the internally ultra-fast bootstrap diode of the 2EDL23I06PJ. To ensure that the bootstrap capacitor is charged before the high side IGBT is switched on, the low side IGBT has to be switched on for a dedicated time of several milliseconds.

3.2 Undervoltage lockout

The +15V supply VDD is monitored by the 2EDL23I06PJ. In case of an undervoltage the driver output is switched off. The thresholds for the low side are typically $V_{CCUV+} = 12.5\text{ V}$ (positive going) and $V_{CCUV-} = 11.6\text{ V}$ (negative going). The thresholds for the high side are typically $V_{BSUV+} = 11.6\text{ V}$ (positive going) and $V_{BSUV-} = 10.7\text{ V}$ (negative going). The undervoltage lockout state of the input section is indicated by the /FAULT LED.

3.3 Short circuit detection

The 2EDL23I06PJ provides integrated short circuit detection by measuring the voltage drop over a 20mΩ shunt. If the current reaches a value of typ. 22.7A a short circuit is detected, and the gate driver outputs are switched off. This status is reported by the /FAULT LED. The /FAULT event is latched by the flip-flop according to Figure 3 and must be reset by activating the reset contactor.

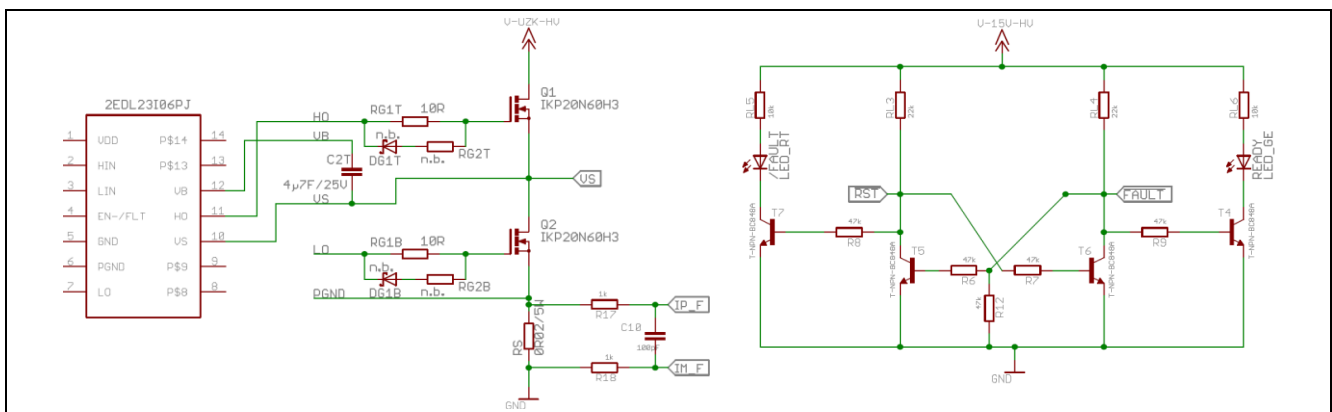


Figure 3 Shunt interface to Opamp and flip-flop latch circuit

Figure 4 shows the signals of the bottom side driver and IGBT during an overcurrent condition. The delay between over current event and output switch off is about 2.2 μs. The FAULT status is latched by an internal logic and must be reset by switching the RESET signal to ground.

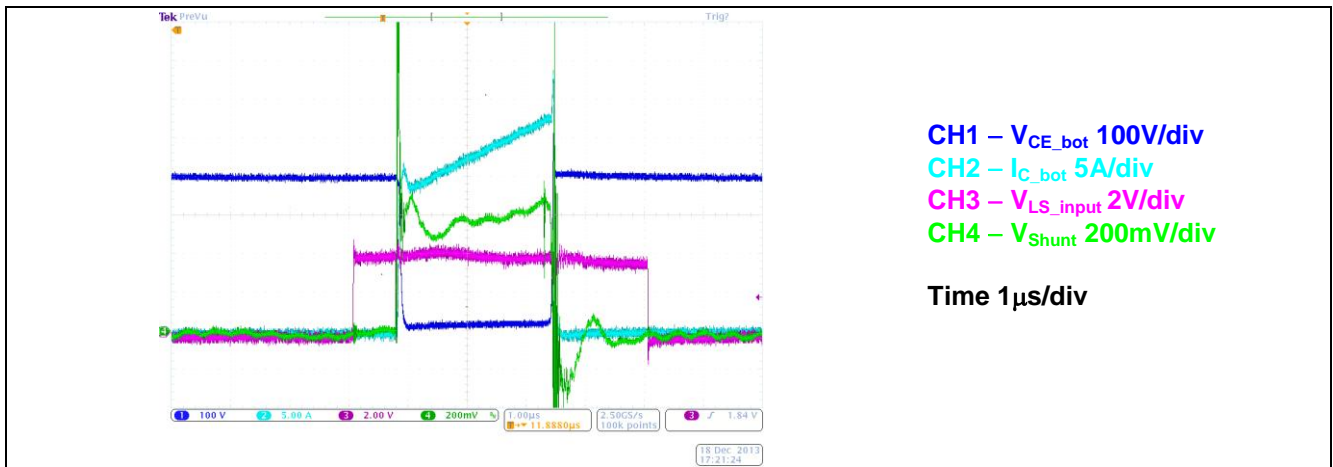


Figure 4 Overcurrent detection signals

3.4 Current amplifier

The EVAL-2EDL23I06PJ provides an operational amplifier which amplifies the voltage drop over the shunt with a gain of 10. The amplified voltage is available for the user at connector X1 pins A9 and B9. The amplified voltage is calculated by the following equation: $V = I_{shunt} \times R_{shunt} \times 10$. Due to inherent component tolerances, the amplifier output should be calibrated in case of using it for a critical current control.

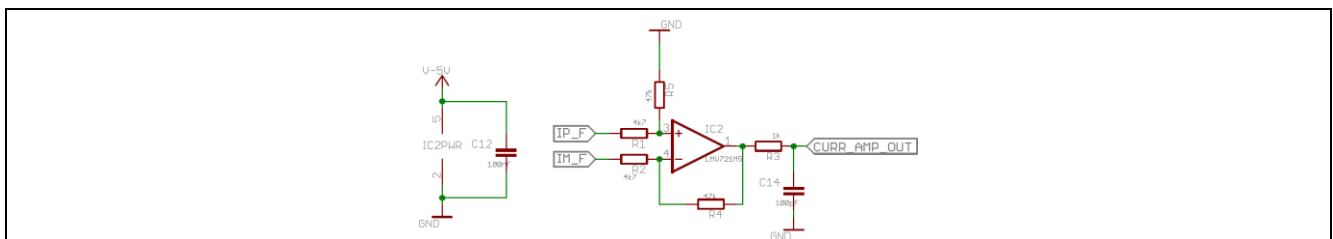


Figure 5 Current amplifier

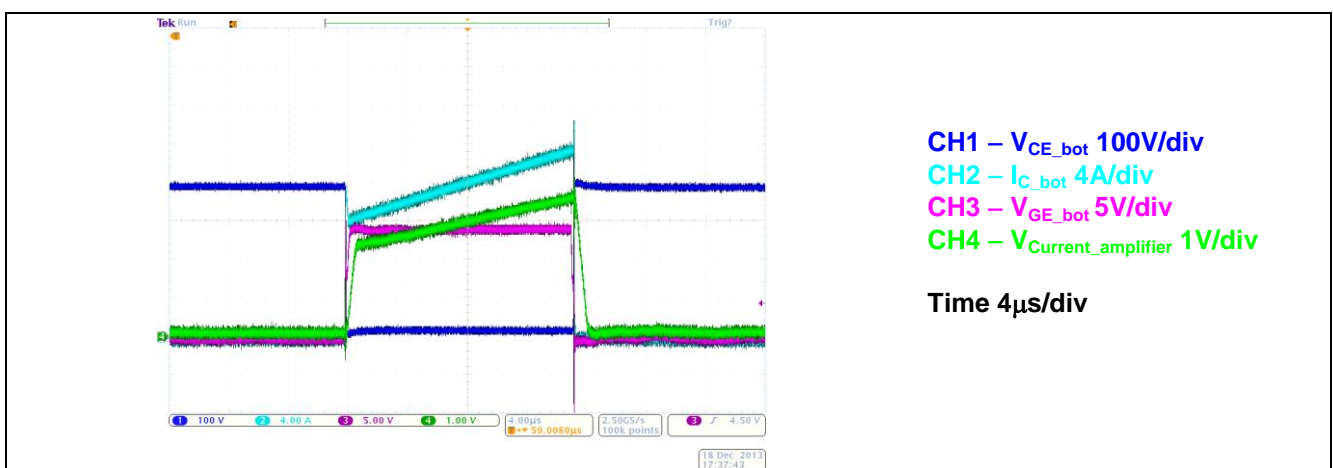


Figure 6 Current amplifier output with collector current

3.5 Deadtime and interlock function

The IC provides a hardware fixed deadtime of typ 380ns. An additional interlock function prevents the two outputs from being activated simultaneously. Hardware deadtime does not block shoot-through. It is a basic item to avoid deep shoot through. The general recommendation for dead time is to be approx. 1µs.

3.6 IGBT turn - on / off

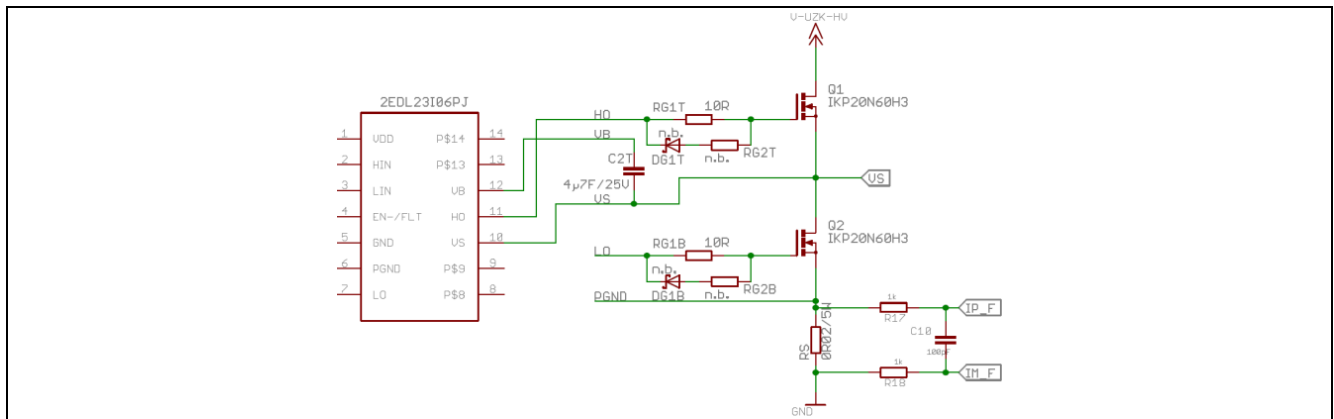


Figure 7 2EDL23I06PJ gate circuit

The switching characteristic of the IGBTs is defined by the gate resistors RG1B, RG1T, RG2B and RG2T according to Figure 7. The resistor values are selected in order to avoid parasitic dv/dt-triggered turn-on. There is the possibility to adapt the switching characteristic to specific applications or to different IGBTs by replacing the values of RG1B and RG1T. The use of RG2B and RG2T together with DG1B and DG1T makes it possible to change the on-switching and the off-switching slopes of the IGBT independent to each other. Please make sure to select an appropriate Schottky diode with sufficient pulse current capability.

The internal deadtime generation of typ. 380ns of the 2EDL23I06PJ ensures that there will be no shoot through between top - and bottom – IGBT. If necessary, a higher deadtime can be generated by the input signals LIN and HIN.

Figure 8 and Figure 9 show typical switching transients for the high side and the low side IGBT.

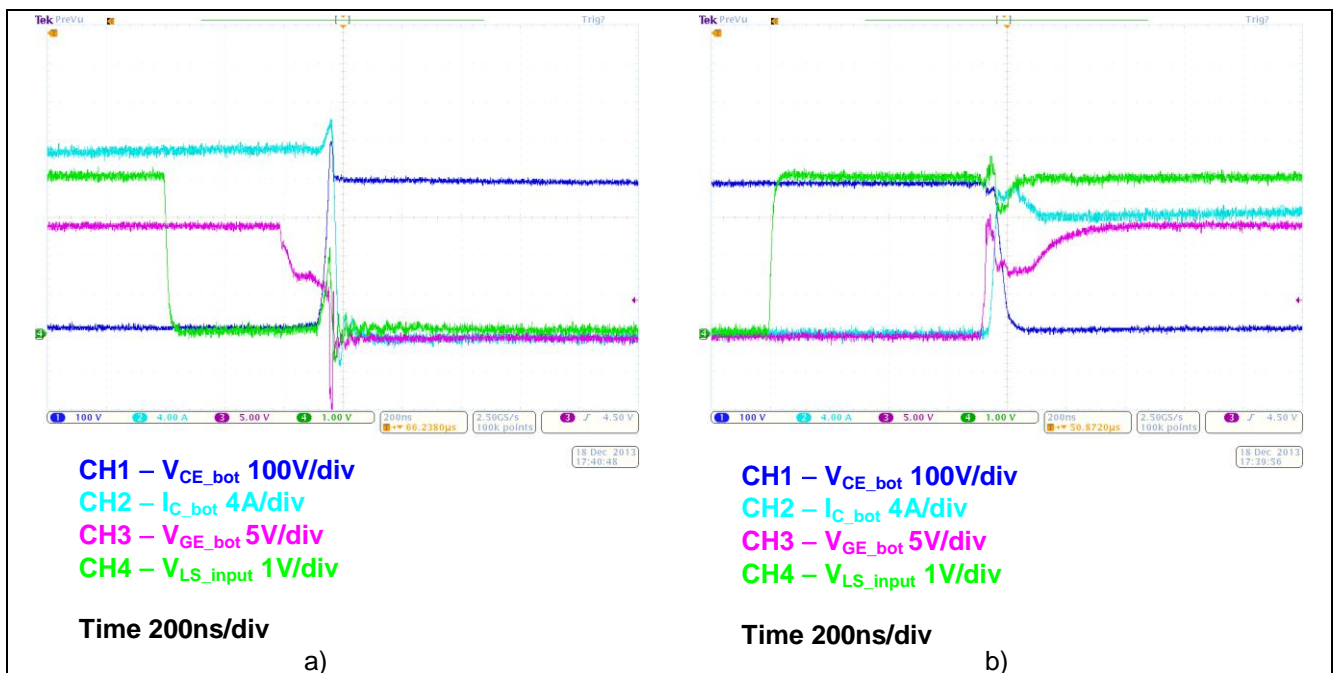


Figure 8 Switching transient of low side IGBT; a) turn-off, b) turn-on

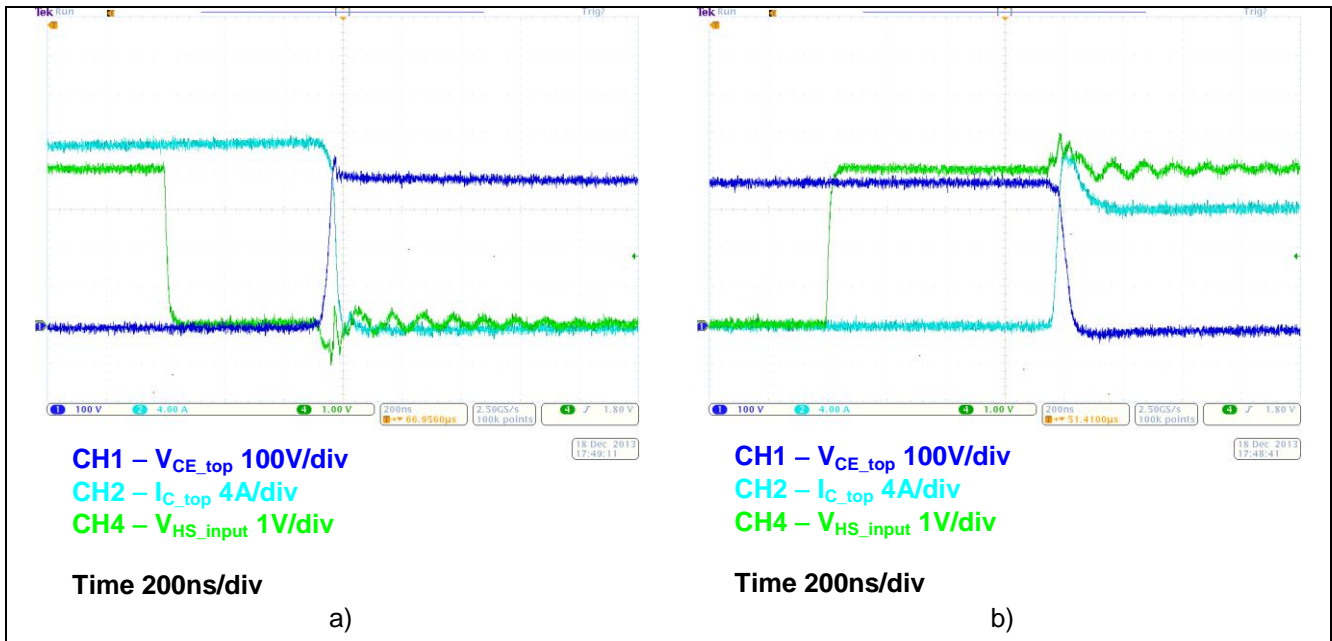


Figure 9 Switching transient of high side IGBT; a) turn-off, b) turn-on

3.7 Input PWM-Signals

There is the possibility to use low pass filters inside the PWM input signals to avoid an undesired turn-on of the IGBT by disturbances. This feature is not used in this evaluation board, but there is the possibility to test it by changing the resistors RIN1T, RIN1B and the capacitors CIN1T, CIN1B. Only the resistors RIN1T and RIN1B are therefore assembled according to Figure 10.

3.8 DC-Link capacitor

Due to the available space there is only a small DC-Link capacitor of 100nF available according to Figure 12. A bigger DC-Link capacitance has to be connected externally to the connectors V+HV and GND_HV to cancel wiring inductances between voltage source and test board.

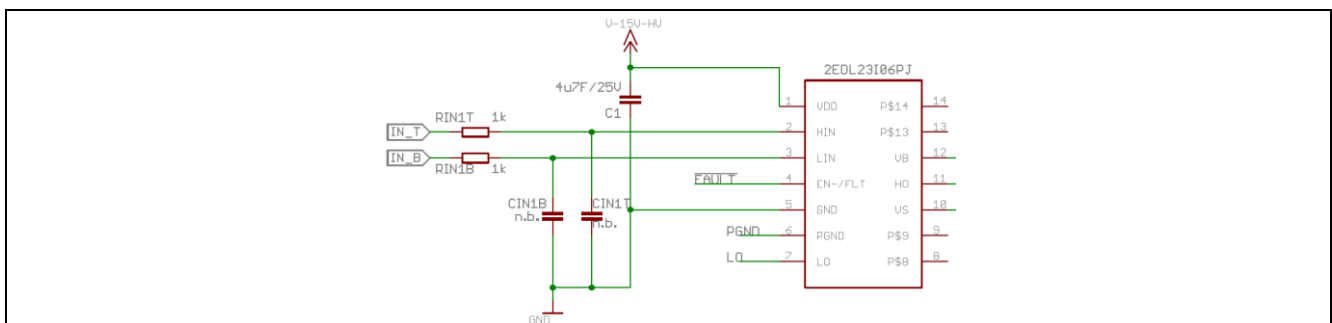


Figure 10 2EDL23I06PJ gate driver input

3.9 Connection of inductive load for non repetitive single or multi pulse measurements

The test board can be used for non-repetitive single or multi pulse measurements. Such kind of measurements help to characterize the switching performance of the used IGBT. **Error! Reference source not found.** shows, how the inductive load must be connected for measuring the high side IGBT in order to keep the overcurrent protection capability.

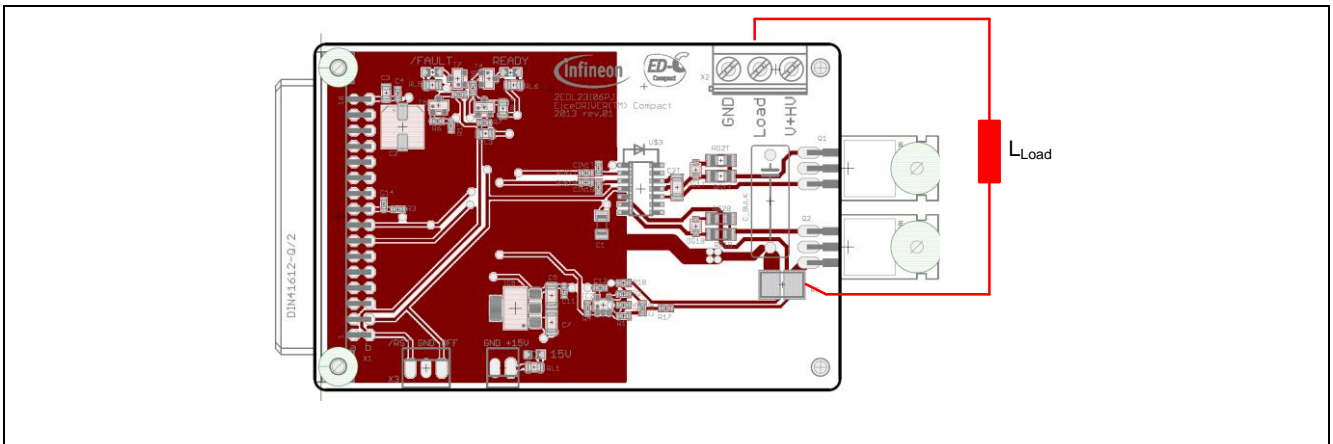


Figure 11 Connection of inductive load

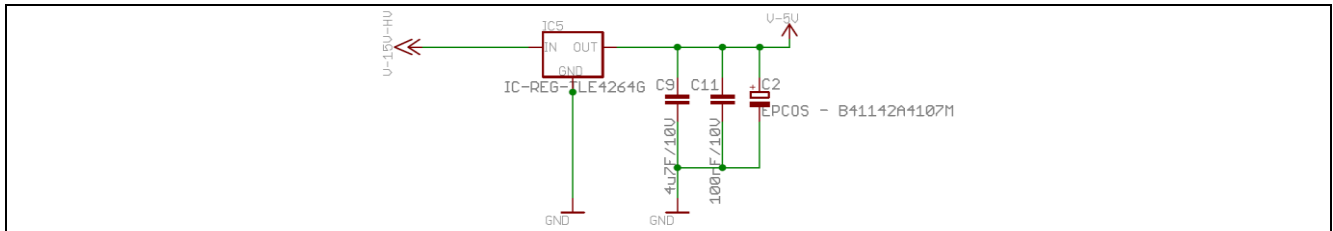


Figure 16 5V voltage regulator

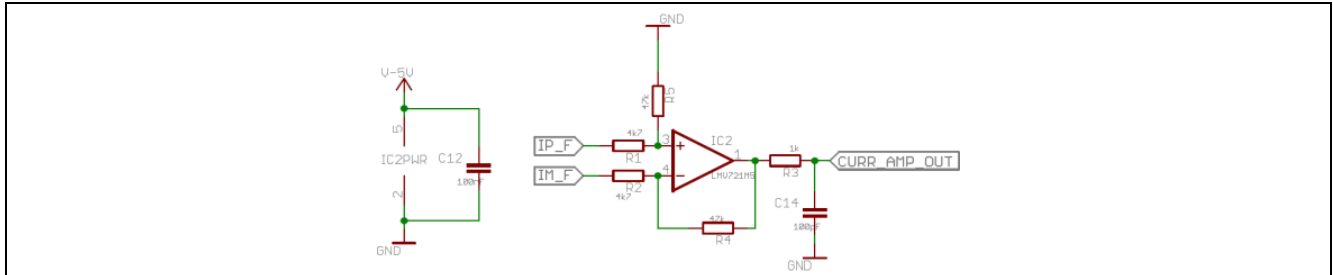


Figure 17 Current amplifier and overcurrent comparator

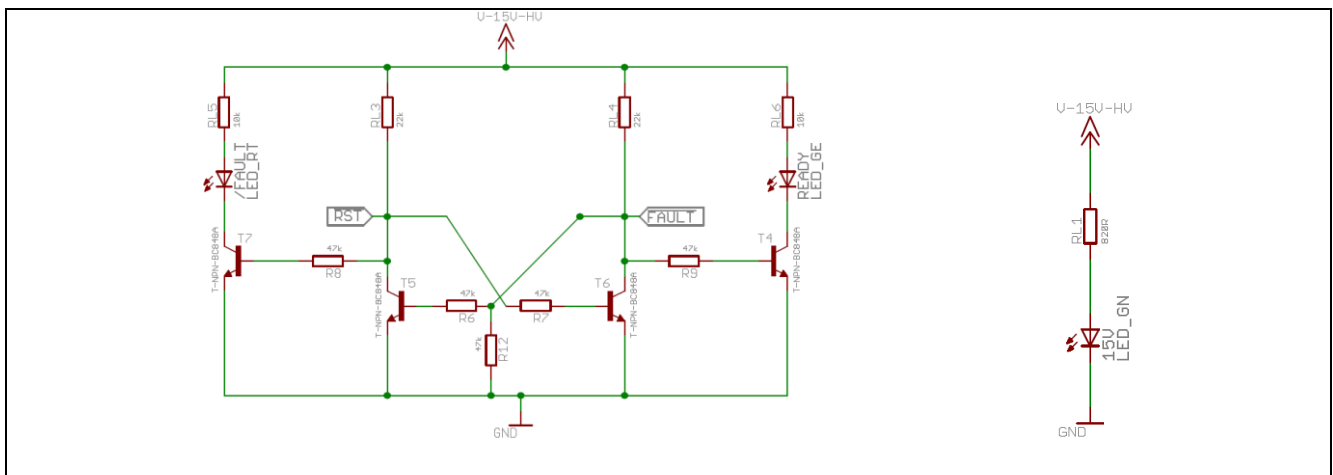


Figure 18 LEDs, FAULT and over current logic

4.2 Layout

4.2.1 Layout top layer

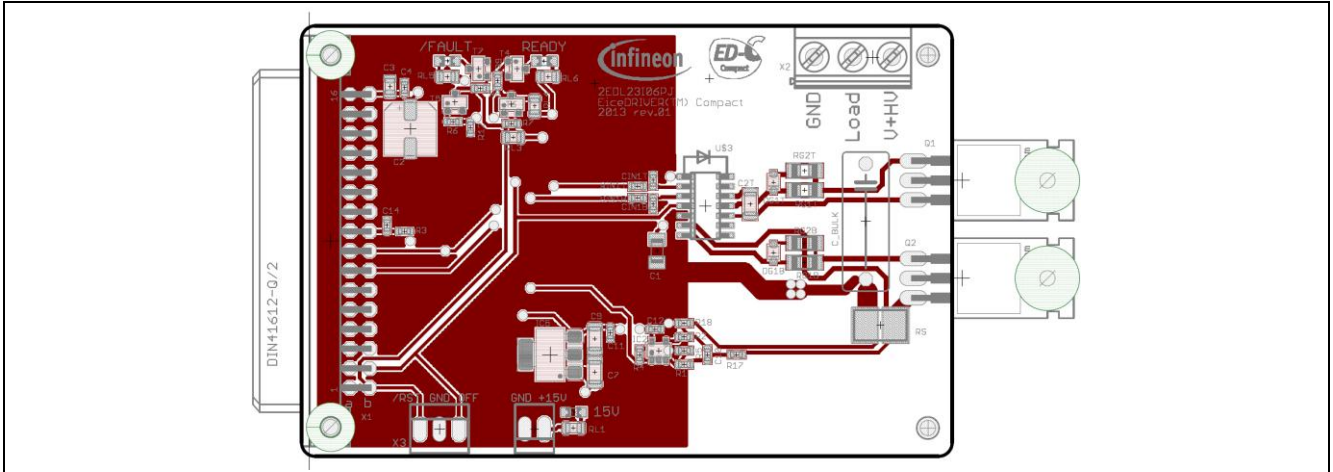


Figure 19 Layout top of the EVAL-2EDL23I06PJ

4.2.2 Layout bottom layer

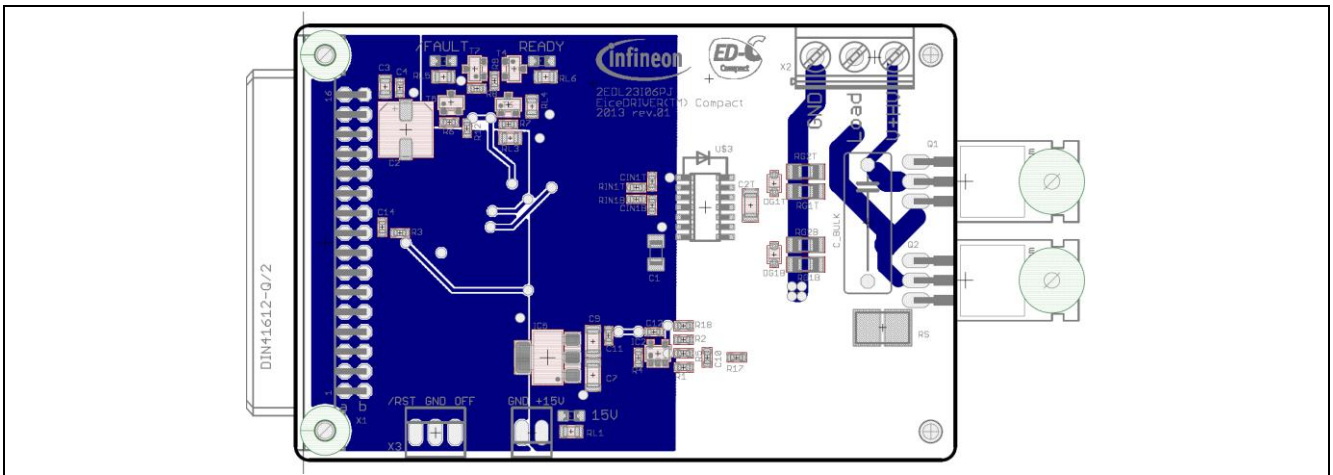


Figure 20 Layout bottom of the EVAL-2EDL23I06PJ

4.2.3 Layout top place

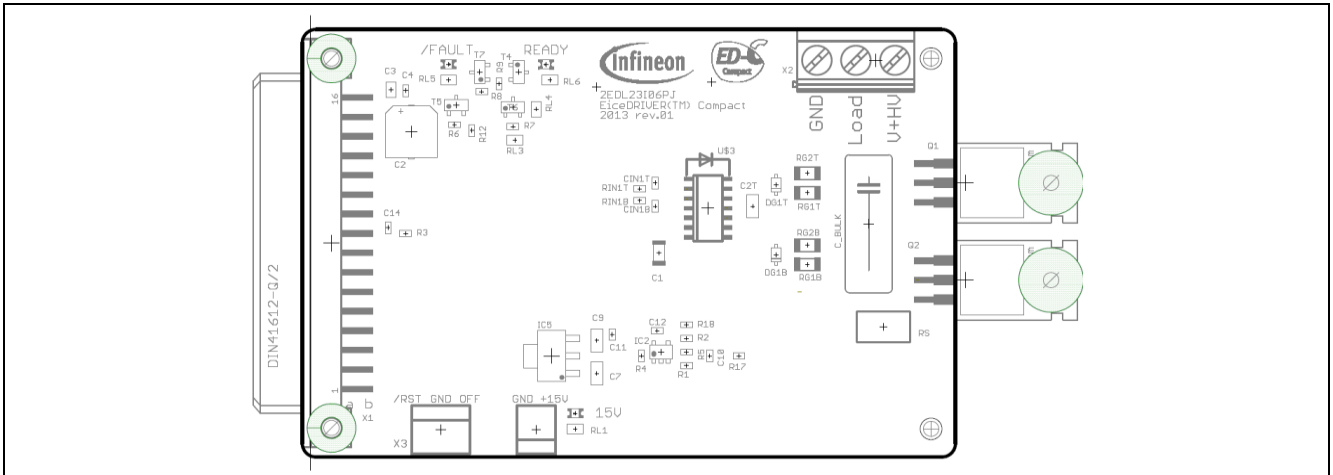


Figure 21 Top place view of the EVAL-2EDL23I06PJ

4.3 Bill of material

| Part | Value | Package |
|-----------------------------|-----------------------|------------------|
| C_BULK | 330nF, 450V | C-EU150-064X183 |
| C1 | 4u7F/25V | C-EUC1206K |
| C10, C14 | 100pF | C-0603 |
| C12 | 100nF | C-0603 |
| C2 | EEEFK1C101P 100µF/16V | SMD-C6.3x7.7 |
| C2T | 4µ7F/25V | C-1206 |
| C3 | 1uF/10V | C-0805 |
| C4, C11 | 100nF/10V | C-0603 |
| C7 | 4u7F/25V | C-1206 |
| C9 | 4u7F/10V | C-1206 |
| IC2 | LMV721M5 | IC-OP-TSV991AILT |
| IC5 | IC-REG-TLE4264G | SOT223 |
| Q1, Q2 | IKP20N60H3 | TO220 |
| R1, R2 | 4k7 | R-0603 |
| R3, R17, R18, RIN1B, RIN1T | 1k | R-0603 |
| R4, R5, R6, R7, R8, R9, R12 | 47k | R-0603 |
| RG1B, RG1T | 10R | R-EU_R1206 |
| RL1 | 820R | R-0805 |
| RL3, RL4 | 22k | R-0805 |
| RL5, RL6 | 10k | R-0805 |
| RS | 0R02/5W | 2012 |
| T4, T5, T6, T7 | T-NPN-BC848A | T-NPN-BC848A |
| U\$3 | 2EDL23I06PJ | 2EDL_SO14-2_3A |
| X1 | FAB32Q2 | FAB32Q2 |
| X2 | MKDSN1,5/3-5,08 | MKDSN1,5/3-5,08 |
| X3 | 22-23-2031 | 22-23-2031 |
| +15V | 22-23-2021 | 22-23-2021 |
| /FAULT | LED_RT | LEDCHIPLED_0805 |
| 15V | LED_GN | LEDCHIPLED_0805 |
| READY | LED_GE | LEDCHIPLED_0805 |

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